Pressure-induced excitations in the out-of-plane optical response of the nodal-line semimetal ZrSiS

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The anisotropic optical response of the layered, nodal-line semimetal ZrSiS at ambient and high pressure is investigated by frequency-dependent reflectivity measurements for the polarization along and perpendicular to the layers. The highly anisotropic optical conductivity is in very good agreement with results from density functional theory calculations and confirms the anisotropic character of ZrSiS. Whereas the in-plane optical conductivity shows only modest pressure-induced changes, we found strong effects on the out-of-plane optical conductivity spectrum of ZrSiS, with the appearance of two prominent excitations. These pronounced pressure-induced effects can neither be attributed to a structural phase transition according to our single-crystal x-ray diffraction measurements, nor can they be explained by electronic correlation and electron-hole pairing effects, as revealed by theoretical calculations. Our findings are discussed in the context of the recently proposed excitonic insulator phase in ZrSiS.

Topological nodal-line semimetals (NLSMs) with linearly dispersing electronic bands, which cross along a line in reciprocal space, host two-dimensional (2D) Dirac fermions and are currently extensively investigated due to their exotic and highly interesting physical properties [1, 2]. The layered material ZrSiS is considered as the prototype NLSM, where the linearly dispersing bands extend over a large energy range ∼2 eV around the Fermi energy E_F, without the presence of topologically trivial bands in the vicinity of E_F, and the corresponding nodal lines form a three-dimensional cage-like structure [3, 4]. There are additional Dirac crossings at the X and R point of the Brillouin zone located ∼0.5 eV above and below E_F, which are protected by nonsymmorphic symmetry against gapping due to the spin-orbit coupling. The unconventional mass enhancement of quasiparticles in ZrSiS [5] suggests the importance of electronic correlations, which could potentially drive the material toward an excitonic insulator phase or a quantum critical region close to it [6, 7].

The exceptional electronic band structure of ZrSiS and related materials ZrXY, where X is a carbon group element (X = Si, Ge, Sn) and Y is a chalcogen element (Y = S, Se, Te) [8], is mainly due to the 2D square nets of Si atoms parallel to the ab-plane, which are the main structural motif besides the square nets of Zr and chalcogen atoms, stacked perpendicular to the ab-plane [see inset of Fig. 1(b)]. Further interesting properties of ZrSiS include high charge carrier mobility and exceptionally large magnetoresistance due to electron-hole symmetry [9, 10]. Also the electrodynamic properties of ZrSiS are unusual, with a nearly frequency-independent optical conductivity σ_1 for frequencies from 250 to 2500 cm^{-1} (30-300 meV) [11, 12]. This rather flat behavior of σ_1 is followed by a U-shaped profile between 3000 and 10.000 cm^{-1} (0.37-1.24 eV), which was ascribed to transitions between the linearly crossing bands of the nodal line close to E_F, and a peak located at ∼11.800 cm^{-1} (∼1.46 eV), associated with transitions between parallel bands of the Dirac crossings protected by nonsymmorphic symmetry [12].

All previous experimental studies on the electrodynamic properties of ZrSiS focused on the in-plane optical response, i.e., for the polarization E of the incident electromagnetic radiation aligned along the layers in the ab-plane [see inset of Fig. 1(b)]. In this paper, we report on the out-of-plane optical conductivity of ZrSiS, as obtained by frequency-dependent reflectivity measurements for E directed perpendicular to the layers, i.e., E[1c]. Furthermore, we studied the in-plane and out-of-plane optical conductivity of ZrSiS under external, quasi-hydrostatic pressure, combined with pressure-dependent single crystal x-ray diffraction (XRD) measurements. In the out-of-plane optical response two new excitations appear under pressure, which cannot be reproduced by density functional theory (DFT) calculations at the generalized gradient approximation [10] level or even by including electronic correlations at GW level and electron-hole pairing effects. Our findings add yet another interesting

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FIG. 1. Optical response functions of ZrSiS at ambient-conditions for polarization directions $E\parallel ab$ and perpendicular ($E\parallel c$) to the layers are depicted in Fig. 1(a). (See the Supplemental Material [17] for a description of sample preparation, experimental details, and analysis of reflectivity data.) For both polarization directions, the reflectivity is high at low energies and shows a distinct plasma edge, indicating the metallic character consistent with recent resistivity measurements [18–19]. The anisotropic character of ZrSiS is manifested by the polarization-dependent energy position of the plasma edge, which is shifted towards lower energies for $E\parallel c$ compared to $E\parallel ab$. Consistently, the intraband plasmon peak in the loss function defined as $\text{Im}(1/\hat{\epsilon})$, where $\hat{\epsilon}$ is the complex dielectric function, appears at lower energy, $\approx0.47 \text{ eV}$, for $E\parallel c$ as compared to $\approx1.07 \text{ eV}$ for $E\parallel ab$ (inset of Fig. 1[a]). The anisotropic optical response is also seen in the real part of the optical conductivity spectrum $\sigma_1$, displayed in Fig. 1(b). For both directions, $\sigma_1$ consists of a Drude term and a rather flat region up to $\approx400 \text{ cm}^{-1}$ followed by a U-shape frequency dependence, which is bounded by a rather sharp peak at high frequencies [14–15]. This sharp peak (called L4 in the following) is associated with transitions between parallel bands of the Dirac crossings, which are protected by nonsymmorphic symmetry against gapping [17]. The profile of the $E\parallel c$ optical conductivity is markedly different: It is rather featureless, namely besides the Drude peak it shows only an absorption peak at $\approx2400 \text{ cm}^{-1}$ and a monotonic increase above $\approx6000 \text{ cm}^{-1}$, which originates from transitions between Dirac bands and states further away from $E_F$. Compared to $E\parallel ab$, the out-of-plane momentum matrix elements exhibit substantially weaker $k$-and band dependence, and thus the $E\parallel c$ optical conductivity reflects the behaviour of the particle-hole (joint) density of states (divided by frequency) [13]. For both directions, the optical conductivity and reflectivity spectra can be well fitted with the Drude-Lorentz model (see Fig. 1). The obtained Drude parameters are given in Refs. [13–18], respectively. Obviously, the charge dynamics and charge transport is much enhanced along the layers compared to the perpendicular direction, as expected.

FIG. 2. Pressure-dependent optical conductivity $\sigma_1$ with the Drude-Lorentz fitting and the corresponding contributions at 0 GPa for (a) $E\parallel ab$ and (b) $E\parallel c$. Arrows mark the most pronounced pressure-induced changes in the spectra. Inset of (a): Comparison between the experimental and both DFT and BSE calculated interband conductivity $\sigma_{1,\text{interband}}$ at 0 GPa.
and Lorentz contributions at ambient pressure are shown in Fig. 2(a) and (b) for $E\parallel ab$ and $E\parallel c$, respectively. For comparison with the results of DFT calculations (see the Suppl. Material [17] for details) we subtracted the Drude term from the total $\sigma_1$ spectrum and obtained the contributions from the interband transitions, $\sigma_{1,\text{interband}}$. The interband conductivity spectra agree well with the corresponding theoretical spectra [see inset of Fig. 2(a)].

In the following, the main focus will be on the optical response of ZrSiS under external pressure. The experimental in-plane and out-of-plane $\sigma_1$ spectra are depicted for selected pressures in Figs. 2(a) and (b), respectively. First, we discuss the results for the in-plane optical response. One notices that the induced changes for $E\parallel ab$ are only modest, and the characteristic profile of the optical conductivity with its U-shape is unchanged up to 7 GPa. A detailed analysis reveals a slight increase of $\sigma_1$ below $\sim 3000$ cm$^{-1}$ and a shift of the L4 peak to higher energies with increasing pressure. A comparison between the experimental and theoretical interband optical conductivity from DFT calculations for $E\parallel ab$ is given in Fig. 3(a) for two selected pressures (2.0 and 7.0 GPa). Like for the experimental results, the U-shape of the theoretical spectrum is retained up to the highest measured pressure and the L4 peak at the high-energy bound of the U-shape is blue-shifted. According to the behavior of the L4 peak, pressure induces a shift of the nonsymmorphic symmetry protected Dirac crossings away from $E_F$, as a result of the compression of the crystal lattice.

Consistently, the thermal contraction of the crystal lattice during cooling causes a blue shift of the L4 peak [see Fig. 3(c)] [22]. A comparison between the effect of cooling and pressure on the energy position of the L4 peak is given in Fig. 3(d), whereby for the latter both experimental and DFT results are displayed [23]. To conclude, tensile strain, instead of compressive strain, would be needed to push the non-symmorphic symmetry protected Dirac nodes in ZrSiS toward $E_F$, in order to study the expected distinct physics related to these 2D Dirac fermions [21].

Next, we will discuss the pressure-induced effects on the out-of-plane optical conductivity [see Fig. 2(b)]. Starting from the lowest applied pressure (2 GPa), drastic changes occur in the profile of the $E\parallel c$ $\sigma_1$ spectrum: besides the pressure-induced increase below $\sim 5000$ cm$^{-1}$, two new excitations labelled F1 and F2 appear, which gain spectral weight with increasing pressure [25]. Similar to the in-plane optical response, a Drude-Lorentz model was applied for fitting the experimental spectra. As an example, we depict in Fig. 3(b) the experimental interband conductivity $\sigma_{1,\text{interband}}$ at 7 GPa, where the Drude term was subtracted from the total $\sigma_1$, together with the Lorentz contributions. Each of the two new excitations F1 and F2 can be well described by one Lorentzian term. With increasing pressure, the energy position of excitation F2 is almost unchanged, whereas F1 first shifts slightly to lower energies for pressures up to $\sim 4$ GPa, and for pressures above 4 GPa this redshift gets more pronounced [Fig. 3(c)]. The oscillator strength of F1 and F2 slightly increases with increasing pressure up to 4 GPa and increases strongly above $\sim 4$ GPa [inset of Fig. 3(c)] due to a transfer of spectral weight from the energy range above $\sim 1.9$ eV. In Fig. 3(b) we compare the experimental $E\parallel c$ $\sigma_{1,\text{interband}}$ spectrum for two selected pressures 2.0 and 7.0 GPa with the corresponding DFT results. Interestingly, the theoretical interband conductivity for $E\parallel c$ is basically unchanged upon pressure application, in strong contrast to the experimental results. In particular, the two excitations F1 and F2 are not reproduced in the pressure-dependent theoretical spectra. Thus, the excitations F1 and F2 should be attributed to effects, which are not included in the band structure calculations, and hence the role of beyond-DFT effects might be relevant, as discussed below.

For an interpretation of our findings, we performed a high-pressure XRD study on a ZrSiS single crystal (see the Suppl. Material [17] for details). With increasing pressure, the lattice parameters $a$ and $c$ monotonically decrease, resulting in a monotonic volume decrease [see Fig. 3(f)]. Further investigation of the reciprocal space might be relevant, as discussed below. According to the behavior of the L4 peak, pressure induces a shift of the nonsymmorphic symmetry protected Dirac crossings away from $E_F$, as a result of the compression of the crystal lattice.

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coupling scenario (formally similar to BCS superconductivity), the electronic band structure, which gives rise to an excitonic insulator phase, where the formation of a single exciton thus cannot explain our experimental results. A more complex possibility would be extending the BSE analysis to finite momentum transfer.

Another scenario was proposed recently [9] suggesting that ZrSiS should be located in a quantum critical region between the NLSM and excitonic insulator phases, which could explain the observed quasiparticle mass enhancement [8] in the absence of a pseudogap, consistent with reported photoemission spectra and our optical data. Nevertheless, both the excitonic insulator and quantum critical scenarios are at odds with our optical results of DFT calculations. The in-plane optical response of the NLSM ZrSiS is highly anisotropic.

In conclusion, according to our reflectivity study, the optical response of the NLSM ZrSiS is highly anisotropic. The polarization-dependent optical conductivity at ambient pressure is in very good agreement with the results of DFT calculations. The in-plane optical response shows only modest changes under pressure, consistent with theoretical predictions. In stark contrast, the out-of-plane electric dipole moments arranged in an antiferroelectric pattern was recently proposed in bulk MoS2 under pressure [30], which might be relevant for pressurized ZrSiS as well.

![Diagram](image77x498to551x729.png)

**FIG. 3.** (a),(b) Comparison between the experimental and DFT interband conductivity $\sigma_{1,\text{interband}}$ at 2.0 and 7.0 GPa, with the total fitting curve and the fitting contributions for the experimental $\sigma_{1,\text{interband}}$ at 7.0 GPa, for $E||ab$ and $E||c$, respectively. Insets of (a),(b): Comparison between DFT and BSE theoretical results and experimental interband conductivity $\sigma_1$ at 7.0 GPa for $E||ab$ and $E||c$, respectively. (c) Temperature-dependent high-energy optical conductivity for $E||ab$. The arrow marks the temperature-induced shift of the L4 peak. (d) Comparison between the temperature ($T$) and pressure ($P$) dependence (both experimental and theoretical) of the frequency position of the L4 peak. (e) Pressure-dependent frequency position and oscillator strength (inset) of the peaks F1 and F2. (f) Volume $V$ of the unit cell and lattice parameters $a$ and $b$ as a function of pressure. The solid line is a fit with a Murnaghan-type EOS (see text).
of-plane optical conductivity undergoes strong changes under pressure, with the appearance of two pronounced peaks. The observed pressure-induced changes can neither be attributed to a structural phase transition according to our single-crystal XRD data, nor can they be explained by electronic correlation effects and single exciton formation according to our theoretical calculations.

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[17] See Supplemental Material at — for details about sample preparation, polarization-dependent reflectivity measurements at ambient and high pressure, analysis of reflectivity and optical conductivity spectra, XRD measurements under pressure, and theoretical calculations, which includes Refs. [34–46].

[22] Please note that we concentrate here on the high-energy range, since the temperature dependence of the low-energy optical conductivity for $\mathbf{E}|ab$ has been discussed in detail in Ref. [44].

[23] It is interesting to note that the temperature-dependent shift of the L4 peak slightly changes its slope between 150 and 100 K. In the same temperature range, the temperature dependence of the dc resistivity changes [28] and several Raman modes show an anomaly in their position and width [28], which was attributed to an interplay between electron and phonon degrees of freedom.


[25] We cannot completely rule out that the F2 peak already exists at ambient pressure, but cannot be resolved due to small oscillator strength and overlap with higher-energy interband transitions.


[32] We note that the F1 peak derives its spectral weight from the high-energy rather than low-energy region. This is opposite to the excitonic insulator scenario, where the spectral weight comes from the Drude peak or low-energy region in general.


